

Automotive P-Channel 30 V (D-S) 175 °C MOSFET

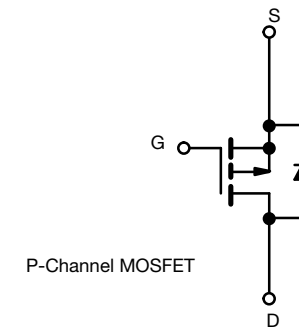
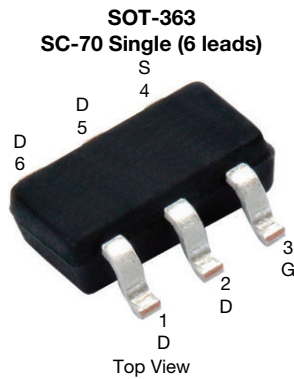
 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE

| PRODUCT SUMMARY | |
|--|--------|
| V_{DS} (V) | -30 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = -10$ V | 0.175 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V | 0.300 |
| I_D (A) | -3 |
| Configuration | Single |
| Package | SC-70 |

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified °
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912


Marking Code: 9E

| ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted) | | | | |
|---|----------------|----------------|------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | | V_{DS} | -30 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current | $T_C = 25$ °C | I_D | -3 | A |
| | $T_C = 125$ °C | | -1.8 | |
| Continuous Source Current (Diode Conduction) | | I_S | -3.7 | |
| Pulsed Drain Current ^a | | I_{DM} | -12 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I_{AS} | -6 | |
| Single Pulse Avalanche Energy | | E_{AS} | 1.8 | |
| Maximum Power Dissipation ^a | $T_C = 25$ °C | P_D | 3 | W |
| | $T_C = 125$ °C | | 1 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to 175 | °C |

| THERMAL RESISTANCE RATINGS | | | | |
|----------------------------|------------------------|------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB Mount ^b | R_{thJA} | 130 | °C/W |
| Junction-to-Foot (Drain) | | R_{thJF} | 50 | |

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).
- Parametric verification ongoing.



| SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | | |
|---|--------------|--|---|------|-------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$ | | -30 | - | - | V |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$ | | -1 | -1.5 | -2 | |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$ | | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$ | - | - | -1 | μA |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$, $T_J = 125\text{ }^\circ\text{C}$ | - | - | -50 | |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = -30\text{ V}$, $T_J = 175\text{ }^\circ\text{C}$ | - | - | -150 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{GS} = -10\text{ V}$ | $V_{DS} \leq -5\text{ V}$ | -5 | - | - | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = -10\text{ V}$ | $I_D = -2\text{ A}$ | - | 0.125 | 0.175 | Ω |
| | | $V_{GS} = -10\text{ V}$ | $I_D = -2\text{ A}$, $T_J = 125\text{ }^\circ\text{C}$ | - | - | 0.252 | |
| | | $V_{GS} = -10\text{ V}$ | $I_D = -2\text{ A}$, $T_J = 175\text{ }^\circ\text{C}$ | - | - | 0.294 | |
| | | $V_{GS} = -4.5\text{ V}$ | $I_D = -1.6\text{ A}$ | - | 0.230 | 0.300 | |
| Forward Transconductance ^b | g_{fs} | $V_{DS} = -10\text{ V}$, $I_D = -2\text{ A}$ | | - | 3 | - | S |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0\text{ V}$ | $V_{DS} = -25\text{ V}$, $f = 1\text{ MHz}$ | - | 164 | 205 | μF |
| Output Capacitance | C_{oss} | | | - | 44 | 55 | |
| Reverse Transfer Capacitance | C_{rss} | | | - | 28 | 35 | |
| Total Gate Charge ^c | Q_g | $V_{GS} = -4.5\text{ V}$ | $V_{DS} = -15\text{ V}$, $I_D = -2.2\text{ A}$ | - | 4.2 | 6.5 | nC |
| Gate-Source Charge ^c | Q_{gs} | | | - | 0.7 | - | |
| Gate-Drain Charge ^c | Q_{gd} | | | - | 1 | - | |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | | 4.5 | 12.5 | 18.5 | Ω |
| Turn-On Delay Time ^c | $t_{d(on)}$ | $V_{DD} = -15\text{ V}$, $R_L = 15\text{ }\Omega$ $I_D \cong -1\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 1\text{ }\Omega$ | | - | 5 | 8 | ns |
| Rise Time ^c | t_r | | | - | 8 | 12 | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | | | - | 11 | 17 | |
| Fall Time ^c | t_f | | | - | 8 | 12 | |
| Source-Drain Diode Ratings and Characteristics ^b | | | | | | | |
| Pulsed Current ^a | I_{SM} | | | - | - | -12 | A |
| Forward Voltage | V_{SD} | $I_F = -1.2\text{ A}$, $V_{GS} = 0\text{ V}$ | | - | -0.85 | -1.2 | V |

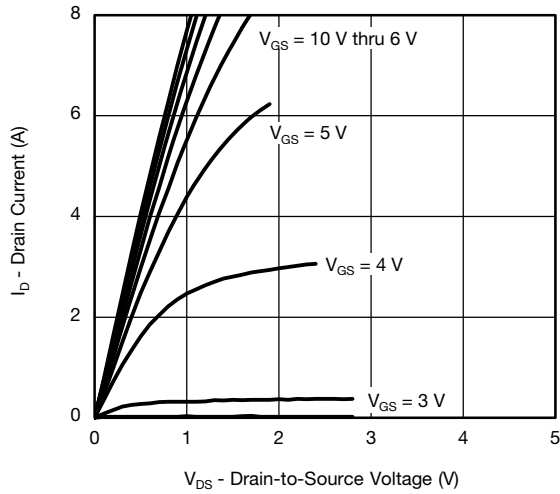
Notes

- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

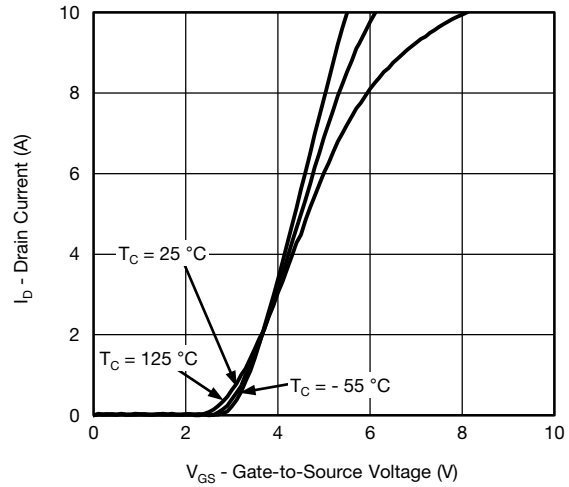
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



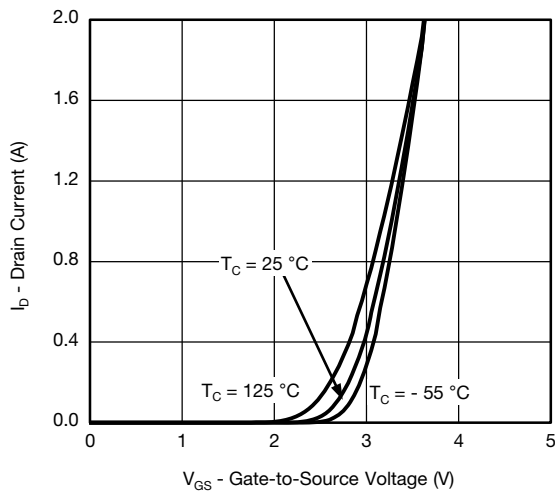
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



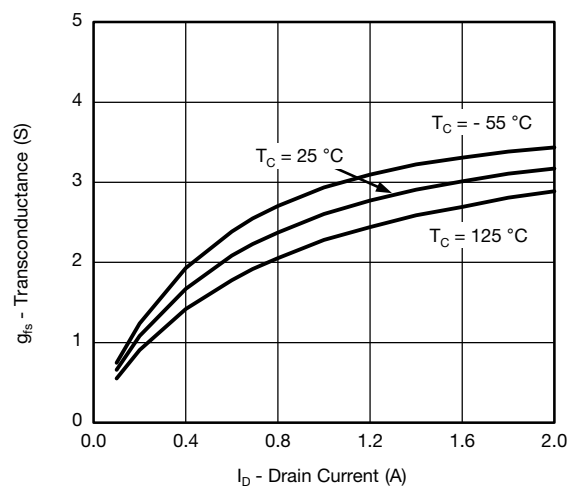
Output Characteristics



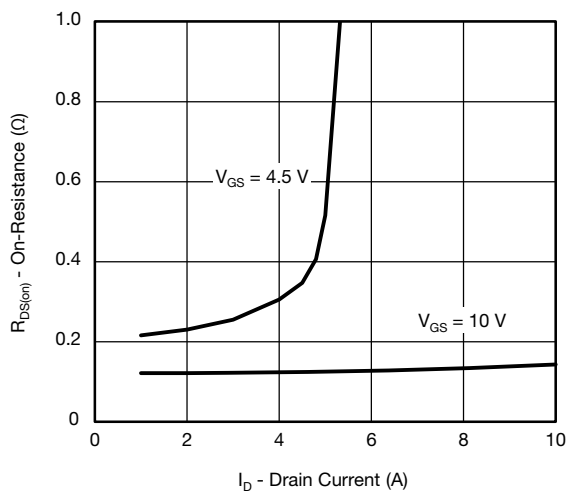
Transfer Characteristics



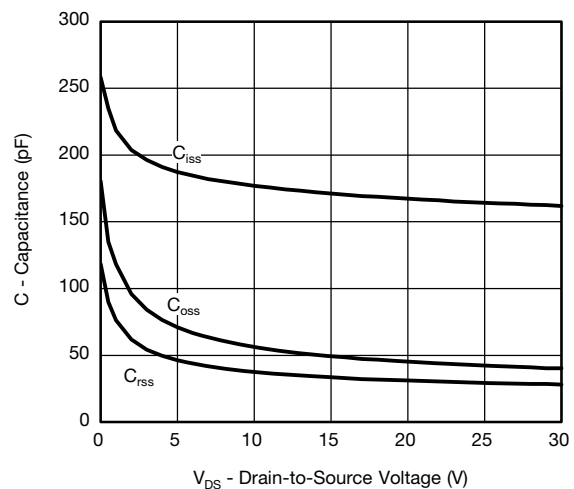
Transfer Characteristics



Transconductance



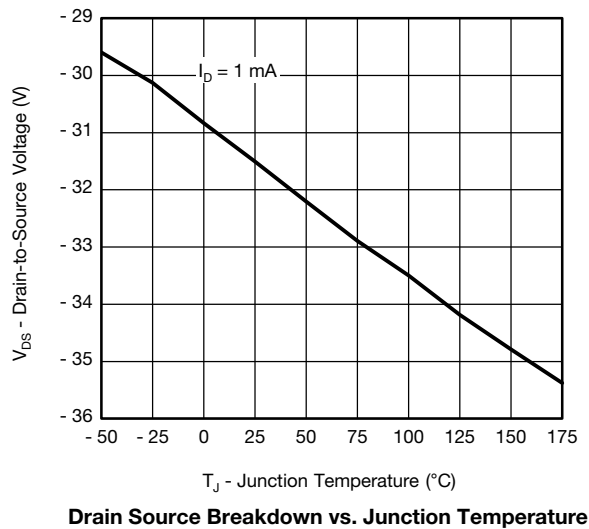
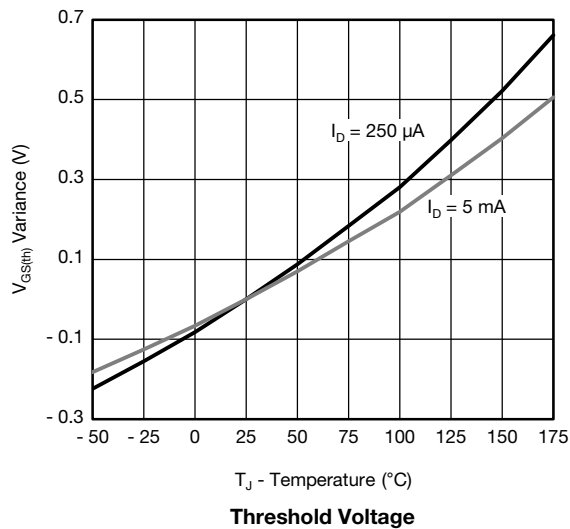
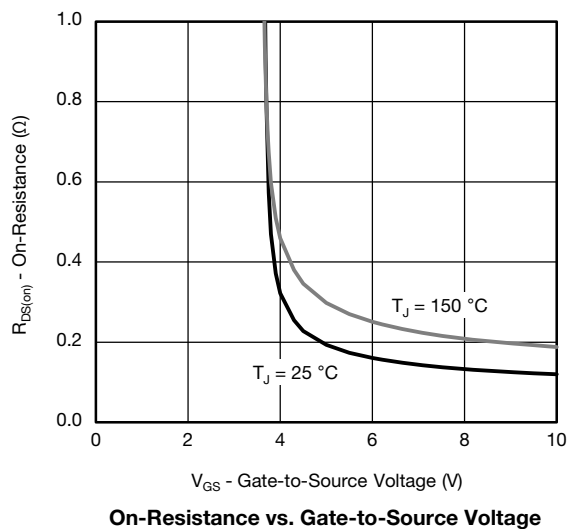
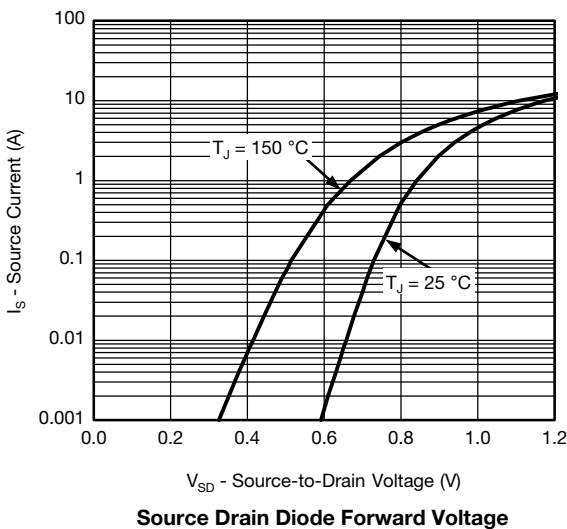
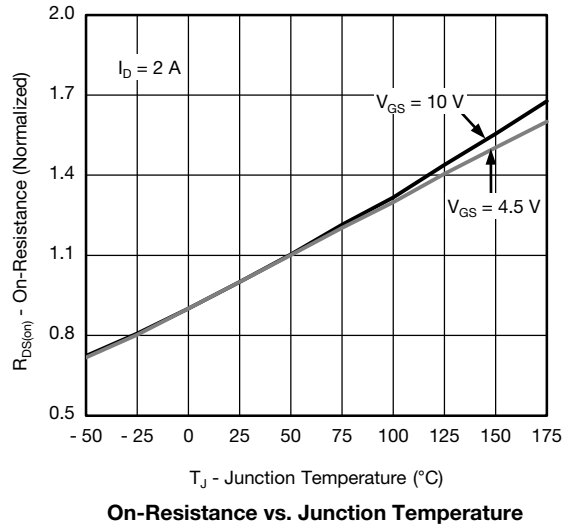
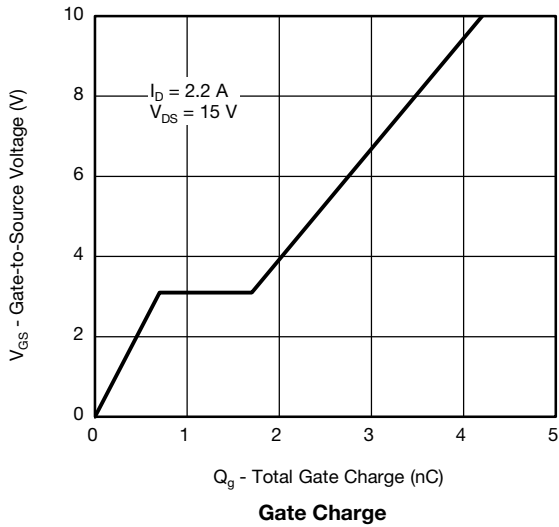
On-Resistance vs. Drain Current



Capacitance

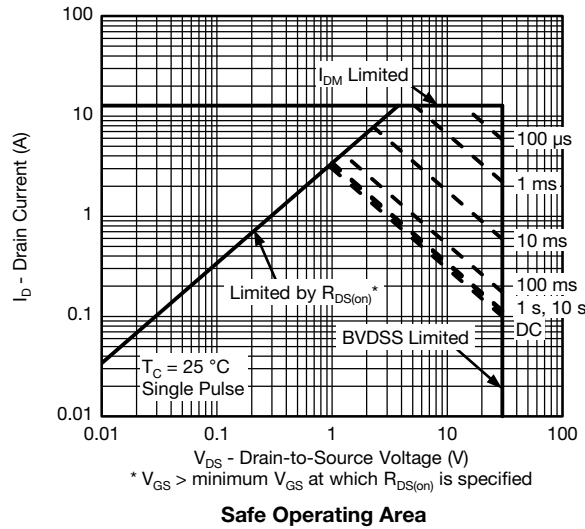


TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)

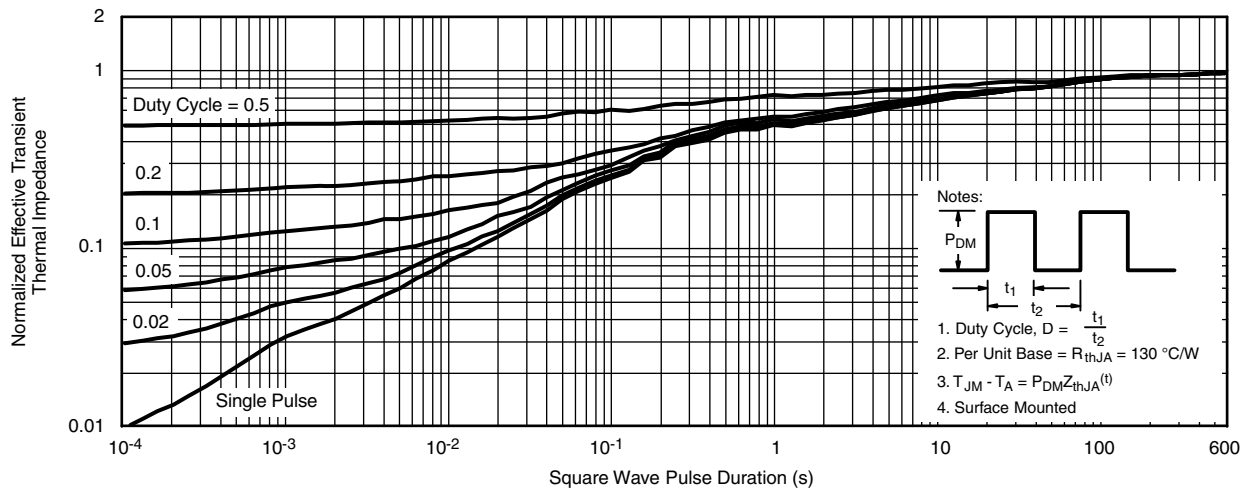




THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



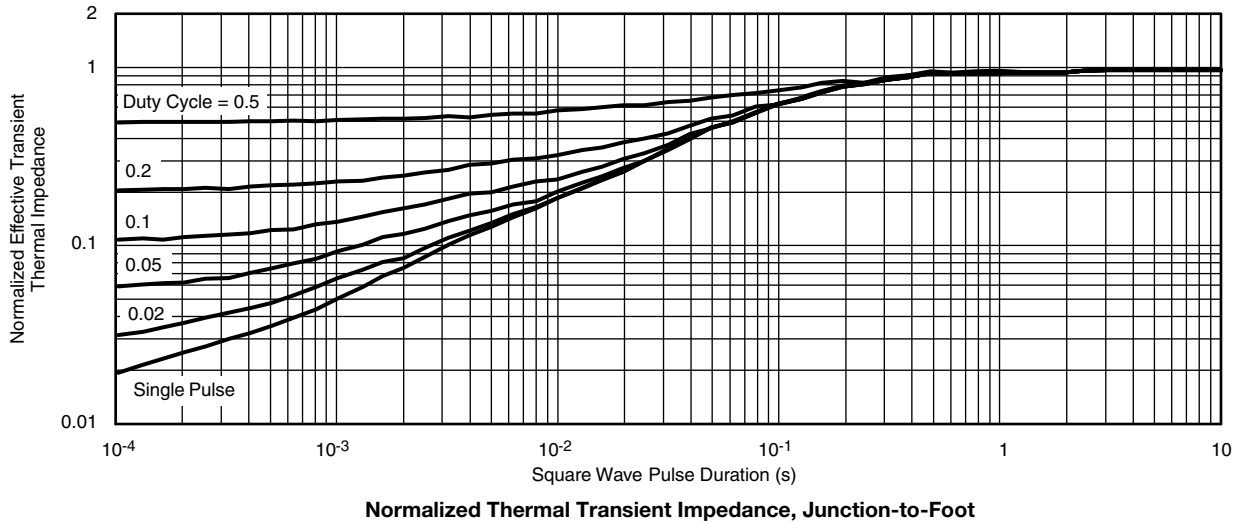
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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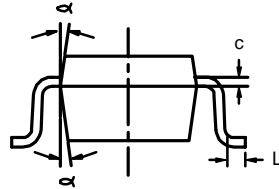
| REVISION HISTORY ^a | | |
|-------------------------------|-----------|----------------------------------|
| REVISION | DATE | DESCRIPTION OF CHANGE |
| C | 03-Dec-15 | • Changed R _g minimum |

Note

a. As of April 2014



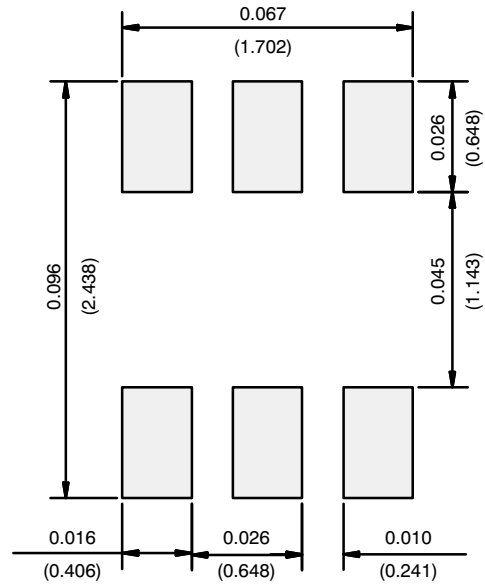
SC-70: 6-LEADS



| Dim | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|----------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.90 | - | 1.10 | 0.035 | - | 0.043 |
| A ₁ | - | - | 0.10 | - | - | 0.004 |
| A ₂ | 0.80 | - | 1.00 | 0.031 | - | 0.039 |
| b | 0.15 | - | 0.30 | 0.006 | - | 0.012 |
| c | 0.10 | - | 0.25 | 0.004 | - | 0.010 |
| D | 1.80 | 2.00 | 2.20 | 0.071 | 0.079 | 0.087 |
| E | 1.80 | 2.10 | 2.40 | 0.071 | 0.083 | 0.094 |
| E ₁ | 1.15 | 1.25 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 0.65BSC | | | 0.026BSC | | |
| e ₁ | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| α | 7°Nom | | | 7°Nom | | |

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5550

RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



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